



**THE DATASHEET OF  
DF262-250-16\_D37MM**





**TET ESTEL AS**  
ESTONIA

**May**  
**2015**

**Series**  
**DF262-250**  
**DF262-250X**

**Fast Recovery Stud-Mounted**  
**Diodes**  
**Type DF262-250,**  
**DF262-250X**

For use as high-power inverters,  
fly-wheel diodes in DC choppers,  
power supplies as high frequency rectifier

Maximum mean forward current							$I_{FAV}$	<b>250 A</b>					
Maximum repetitive peak reverse voltage							$U_{RRM}$	<b>600 ÷ 1600 V</b>					
Reverse recovery time							<b>trr</b>	<b>2,0; 2,5; 3,2 μs</b>					
$U_{RRM}, V$	600	700	800	900	1000	1100	1200	1300	1400	1500	1600		
Voltage code	6	7	8	9	10	11	12	13	14	15	16		
$T_{vj}, °C$	- 60 ÷ 125												

**MAXIMUM ALLOWABLE RATINGS**

Symbols and parameters		Units	DF262-250 DF262-250X	Conditions
$I_{FAV}$	Mean forward current	A	250 380	$T_c=84°C,$ $T_c=55°C,$ 180° half-sine wave, 50 Hz
$I_{FRMS}$	RMS forward current	A	392	$T_c=84°C$
$I_{FSM}$	Surge forward current	kA	4,5 5,0	$T_{vj}=125°C$ $T_{vj}= 25°C$ tp=10 ms
$I^2t$	Limiting load integral	$kA^2s$	101 125	$T_{vj}=125°C$ $T_{vj}= 25°C$ UR=0
$U_{RRM}$	Repetitive peak reverse voltage	V	600 ÷ 1600	$T_j \min \leq T_{vj} \leq T_{jM}$ 180° half-sine wave, 50 Hz
$U_{RSM}$	Non-repetitive peak reverse voltage	V	660 ÷ 1700	$T_j \min \leq T_{vj} \leq T_{jM}$ 180° half-sine wave tp=10 ms, Single pulse
$T_{stg}$	Storage temperature	°C	-60÷80	
$T_{vj}$	Junction temperature	°C	-60÷125	

**CHARACTERISTICS**

$U_{FM}$	Peak forward voltage	V	1,6	$T_{vj}=25°C, I_{FM}=3,14 I_{FAV}$
$U_{F(TO)}$	Threshold voltage	V	0,97	$T_{vj}=125°C$
$R_T$	Forward slope resistance	mΩ	0,6	1,57 $I_{FAV} < I_F < 4,71 I_{FAV}$
$I_{RRM}$	Repetitive peak reverse current	mA	35	$T_{vj}=125°C,$ $U_R = U_{RRM}$

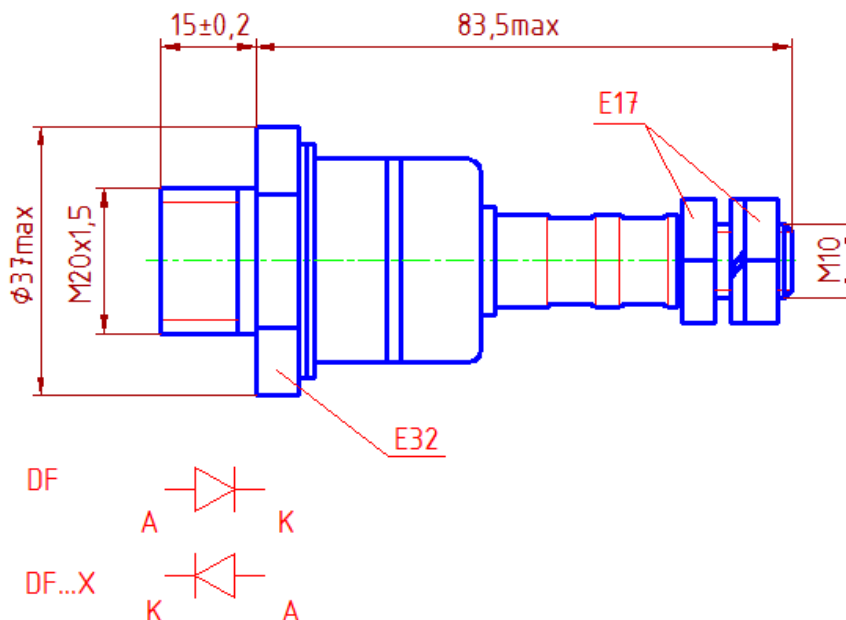
## CHARACTERISTICS

Symbols and parameters		Units	DF262-250 DF262-250X	Conditions
trr	Reverse recovery time	μs	2,0 ÷ 3,2 2,0 ÷ 2,5 1,6 ÷ 2,0	T <sub>vj</sub> =125°C, I <sub>F</sub> =250A, U <sub>R</sub> =100V di <sub>R</sub> / dt = 50 A/μs di <sub>R</sub> / dt = 100 A/μs di <sub>R</sub> / dt = 200 A/μs
Q <sub>rr</sub>	Recovered charge	μC	60 ÷ 100 90 ÷ 140 120 ÷ 160	T <sub>vj</sub> =125°C, I <sub>F</sub> =250A, U <sub>R</sub> =100V di <sub>R</sub> / dt = 50 A/μs di <sub>R</sub> / dt = 100 A/μs di <sub>R</sub> / dt = 200 A/μs
R <sub>thjc</sub>	Thermal resistance junction to case	°C/W	0,12	Direct current

## ORDERING

	DF	262	250	X	14	4
	1	2	3	4	5	6

1. Fast recovery diode.
2. Design version.
3. Mean forward current, A.
4. Reverse polarity (cathode stud mounted), without X-normal polarity.
5. Voltage code (14 = 1400 V).
6. Group of reverse recovery time (3 ≤ 3,2 μs; 4 ≤ 2,5 μs; 5 ≤ 2,0 μs).





Mounting of diodes with a rigid cathode gate should be carried through a flexible conductor.

Tightening torque: 24 ÷ 36 Nm (thread M20x1,5)  
 Tightening torque: 8 ÷ 12 Nm (thread M10)

Weight: 240 grams

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